



TS912

## Rail-to-rail CMOS dual operational amplifier

### Features

- Rail-to-rail input and output voltage ranges
- Single (or dual) supply operation from 2.7V to 16V
- Extremely low input bias current: 1pA typ.
- Low input offset voltage: 2mV max.
- Specified for  $600\Omega$  and  $100\Omega$  loads
- Low supply current:  $200\mu A$ /amp ( $V_{CC} = 3V$ )
- Latch-up immunity
- ESD tolerance: 3kV
- Spice macromodel included in this specification

### Description

The TS912 is a rail-to-rail CMOS dual operational amplifier designed to operate with a single or dual supply voltage.

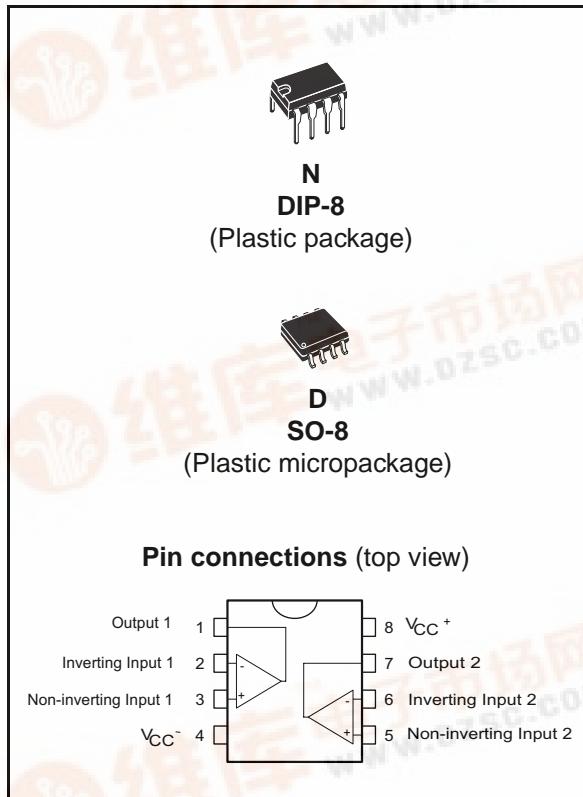
The input voltage range  $V_{icm}$  includes the two supply rails  $V_{CC}^+$  and  $V_{CC}^-$ .

The output reaches:

- $V_{CC}^- +30mV$ ,  $V_{CC}^+ -40mV$ , with  $R_L = 10k\Omega$
- $V_{CC}^- +300mV$ ,  $V_{CC}^+ -400mV$ , with  $R_L = 600\Omega$

This product offers a broad supply voltage operating range from 2.7V to 16V and supply current of only  $200\mu A$ /amp ( $V_{CC} = 3V$ ).

Source and sink output current capability is typically 40mA (at  $V_{CC} = 3V$ ), fixed by an internal limitation circuit.



# 1 Absolute maximum ratings and operating conditions

**Table 1. Absolute maximum ratings**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage <sup>(1)</sup>	18	V
$V_{id}$	Differential input voltage <sup>(2)</sup>	$\pm 18$	V
$V_i$	Input voltage <sup>(3)</sup>	-0.3 to 18	V
$I_{in}$	Current on inputs	$\pm 50$	mA
$I_o$	Current on outputs	$\pm 130$	mA
$T_{stg}$	Storage temperature	-65 to +150	°C
$T_j$	Maximum junction temperature	150	°C
$R_{thja}$	Thermal resistance junction to ambient <sup>(4)</sup> DIP8 SO-8	85 125	°C/W
$R_{thjc}$	Thermal resistance junction to case <sup>(4)</sup> DIP8 SO-8	41 40	°C/W
ESD	HBM: human body model <sup>(5)</sup>	3	kV
	MM: machine model <sup>(6)</sup>	200	V
	CDM: charged device model <sup>(7)</sup>	1500	V

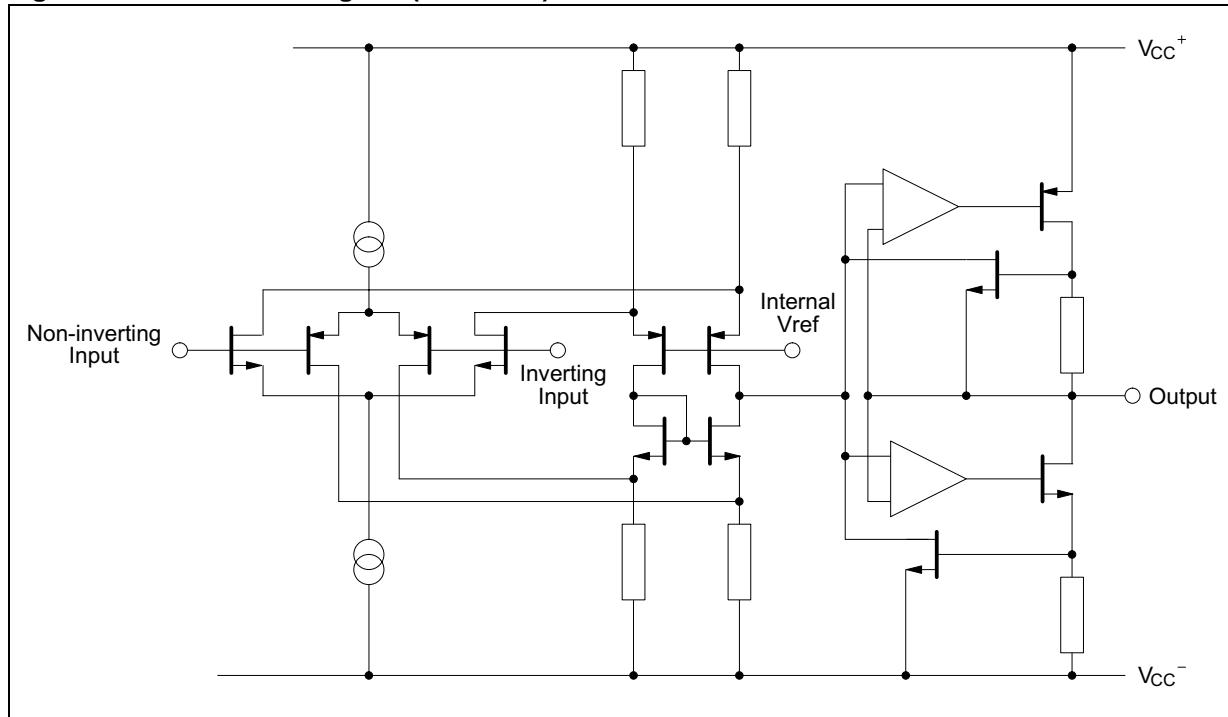
1. All voltage values, except differential voltage are with respect to network ground terminal.
2. Differential voltages are non-inverting input terminal with respect to the inverting input terminal.
3. The magnitude of input and output voltages must never exceed  $V_{CC}^+ + 0.3V$ .
4. Short-circuits can cause excessive heating. Destructive dissipation can result from simultaneous short-circuits on all amplifiers. These values are typical.
5. Human body model: A 100pF capacitor is charged to the specified voltage, then discharged through a 1.5kΩ resistor between two pins of the device. This is done for all couples of connected pin combinations while the other pins are floating.
6. Machine model: A 200pF capacitor is charged to the specified voltage, then discharged directly between two pins of the device with no external series resistor (internal resistor < 5Ω). This is done for all couples of connected pin combinations while the other pins are floating.
7. Charged device model: all pins and the package are charged together to the specified voltage and then discharged directly to the ground through only one pin. This is done for all pins.

**Table 2. Operating conditions**

Symbol	Parameter	Value	Unit
$V_{CC}$	Supply voltage	2.7 to 16	V
$V_{icm}$	Common mode input voltage range	$V_{CC}^- - 0.2$ to $V_{CC}^+ + 0.2$	V
$T_{oper}$	Operating free air temperature range	-40 to + 125	°C

## 2 Schematic diagram

Figure 1. Schematic diagram (1/2 TS912)



### 3 Electrical characteristics

**Table 3.**  $V_{CC}^+ = 3V$ ,  $V_{CC}^- = 0V$ ,  $R_L$ ,  $C_L$  connected to  $V_{CC}/2$ ,  $T_{amb} = 25^\circ C$  (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
$V_{io}$	Input offset voltage ( $V_{ic} = V_o = V_{CC}/2$ ) TS912 TS912A TS912B $T_{min} \leq T_{amb} \leq T_{max}$ TS912 TS912A TS912B			10 5 2 12 7 3	mV
$\Delta V_{io}$	Input offset voltage drift		5		$\mu V/^\circ C$
$I_{io}$	Input offset current <sup>(1)</sup> $T_{min} \leq T_{amb} \leq T_{max}$		1	100 200	pA
$I_{ib}$	Input bias current <sup>(1)</sup> $T_{min} \leq T_{amb} \leq T_{max}$		1	150 300	pA
$I_{CC}$	Supply current (per amplifier, $A_{VCL} = 1$ , no load) $T_{min} \leq T_{amb} \leq T_{max}$		200	300 400	$\mu A$
CMR	Common mode rejection ratio $V_{ic} = 0$ to $3V$ , $V_o = 1.5V$		70		dB
SVR	Supply voltage rejection ratio ( $V_{CC}^+ = 2.7$ to $3.3V$ , $V_o = V_{CC}/2$ )	50	80		dB
$A_{vd}$	Large signal voltage gain ( $R_L = 10k\Omega$ , $V_o = 1.2V$ to $1.8V$ ) $T_{min} \leq T_{amb} \leq T_{max}$	3 2	10		$V/mV$
$V_{OH}$	High level output voltage ( $V_{id} = 1V$ ) $R_L = 100k\Omega$ $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 100\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 10k\Omega$ $R_L = 600\Omega$		2.95 2.9 2.3 2.8 2.1	2.96 2.6 2	V
$V_{OL}$	Low level output voltage ( $V_{id} = -1V$ ) $R_L = 100k\Omega$ $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 100\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 10k\Omega$ $R_L = 600\Omega$		30 300 900	50 70 400 100 600	mV
$I_o$	Output short-circuit current ( $V_{id} = \pm 1V$ ) Source ( $V_o = V_{CC}^-$ ) Sink ( $V_o = V_{CC}^+$ )	20 20	40 40		mA
GBP	Gain bandwidth product ( $A_{VCL} = 100$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $f = 100kHz$ )		0.8		MHz

**Table 3.**  $V_{CC}^+ = 3V$ ,  $V_{CC}^- = 0V$ ,  $R_L$ ,  $C_L$  connected to  $V_{CC}/2$ ,  $T_{amb} = 25^\circ C$  (unless otherwise specified) (continued)

Symbol	Parameter	Min.	Typ.	Max.	Unit
SR <sup>+</sup>	Slew rate ( $A_{VCL} = 1$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $V_i = 1.3V$ to $1.7V$ )		0.4		V/ $\mu$ s
SR <sup>-</sup>	Slew rate ( $A_{VCL} = 1$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $V_i = 1.3V$ to $1.7V$ )		0.3		V/ $\mu$ s
$\phi_m$	Phase margin		30		Degrees
en	Equivalent input noise voltage ( $R_s = 100\Omega$ , $f = 1kHz$ )		30		nV/ $\sqrt{Hz}$

1. Maximum values include unavoidable inaccuracies of the industrial tests.

**Table 4.**  $V_{CC}^+ = 5V$ ,  $V_{CC}^- = 0V$ ,  $R_L$ ,  $C_L$  connected to  $V_{CC}/2$ ,  $T_{amb} = 25^\circ C$  (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
$V_{io}$	Input offset voltage ( $V_{ic} = V_o = V_{CC}/2$ ) TS912 TS912A TS912B $T_{min} \leq T_{amb} \leq T_{max}$ TS912 TS912A TS912B			10 5 2 12 7 3	mV
$\Delta V_{io}$	Input offset voltage drift		5		$\mu V/^\circ C$
$I_{io}$	Input offset current <sup>(1)</sup> $T_{min} \leq T_{amb} \leq T_{max}$		1	100 200	pA
$I_{ib}$	Input bias current <sup>(1)</sup> $T_{min} \leq T_{amb} \leq T_{max}$		1	150 300	pA
$I_{CC}$	Supply current (per amplifier, $A_{VCL} = 1$ , no load) $T_{min} \leq T_{amb} \leq T_{max}$		230	350 450	$\mu A$
CMR	Common mode rejection ratio $V_{ic} = 1.5$ to $3.5V$ , $V_o = 2.5V$	60	85		dB
SVR	Supply voltage rejection ratio ( $V_{CC}^+ = 3$ to $5V$ , $V_o = V_{CC}/2$ )	55	80		dB
$A_{vd}$	Large signal voltage gain ( $R_L = 10k\Omega$ , $V_o = 1.5V$ to $3.5V$ ) $T_{min} \leq T_{amb} \leq T_{max}$	10 7	40		V/mV
$V_{OH}$	High level output voltage ( $V_{id} = 1V$ ) $R_L = 100k\Omega$ $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 100\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 10k\Omega$ $R_L = 600\Omega$		4.95 4.9 4.25 4.8 4.1	4.95 4.55 3.7	V
$V_{OL}$	Low level output voltage ( $V_{id} = -1V$ ) $R_L = 100k\Omega$ $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 100\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 10k\Omega$ $R_L = 600\Omega$		40 350 1400	50 100 500 150 750	mV
$I_o$	Output short-circuit current ( $V_{id} = \pm 1V$ ) Source ( $V_o = V_{CC}^-$ ) Sink ( $V_o = V_{CC}^+$ )	45 45	65 65		mA
GBP	Gain bandwidth product ( $A_{VCL} = 100$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $f = 100kHz$ )		1		MHz
SR <sup>+</sup>	Slew rate ( $A_{VCL} = 1$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $V_i = 1V$ to $4V$ )		0.8		$V/\mu s$
SR <sup>-</sup>	Slew rate ( $A_{VCL} = 1$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $V_i = 1V$ to $4V$ )		0.6		$V/\mu s$

**Table 4.**  $V_{CC}^+ = 5V$ ,  $V_{CC}^- = 0V$ ,  $R_L$ ,  $C_L$  connected to  $V_{CC}/2$ ,  $T_{amb} = 25^\circ C$  (unless otherwise specified) (continued)

Symbol	Parameter	Min.	Typ.	Max.	Unit
en	Equivalent input noise voltage ( $R_s = 100\Omega$ , $f = 1kHz$ )		30		nV/ $\sqrt{Hz}$
$V_{O1}/V_{O2}$	Channel separation ( $f = 1kHz$ )		120		dB
$\phi_m$	Phase margin		30		Degrees

1. Maximum values include unavoidable inaccuracies of the industrial tests.

**Table 5.**  $V_{CC^+} = 10V$ ,  $V_{CC^-} = 0V$ ,  $R_L$ ,  $C_L$  connected to  $V_{CC}/2$ ,  $T_{amb} = 25^\circ C$  (unless otherwise specified)

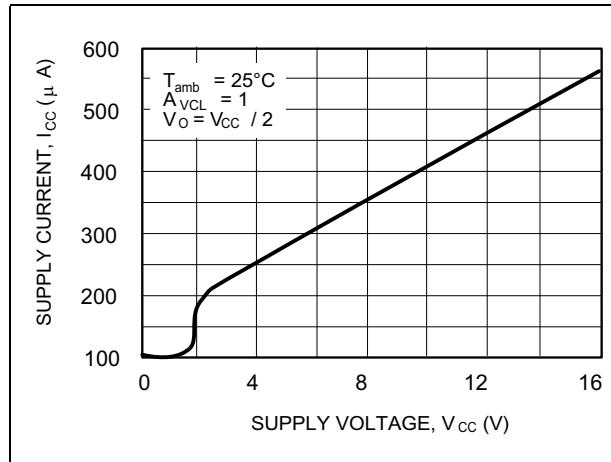
Symbol	Parameter	Min.	Typ.	Max.	Unit
$V_{io}$	Input offset voltage ( $V_{ic} = V_o = V_{CC}/2$ ) TS912 TS912A TS912B $T_{min} \leq T_{amb} \leq T_{max}$ TS912 TS912A TS912B			10 5 2 12 7 3	mV
$\Delta V_{io}$	Input offset voltage drift		5		$\mu V/^\circ C$
$I_{io}$	Input offset current <sup>(1)</sup> $T_{min} \leq T_{amb} \leq T_{max}$		1	100 200	pA
$I_{ib}$	Input bias current <sup>(1)</sup> $T_{min} \leq T_{amb} \leq T_{max}$		1	150 300	pA
$I_{CC}$	Supply current (per amplifier, $A_{VCL} = 1$ , no load) $T_{min} \leq T_{amb} \leq T_{max}$		400	600 700	$\mu A$
CMR	Common mode rejection ratio $V_{ic} = 3$ to $7V$ , $V_o = 5V$ $V_{ic} = 0$ to $10V$ , $V_o = 5V$	60 50	90 75		dB
SVR	Supply voltage rejection ratio ( $V_{CC^+} = 5$ to $10V$ , $V_o = V_{CC}/2$ )	60	90		dB
$A_{vd}$	Large signal voltage gain ( $R_L = 10k\Omega$ $V_o = 2.5V$ to $7.5V$ ) $T_{min} \leq T_{amb} \leq T_{max}$	15 10	50		$V/mV$
$V_{OH}$	High level output voltage ( $V_{id} = 1V$ ) $R_L = 100k\Omega$ $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 100\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 10k\Omega$ $R_L = 600\Omega$	9.95 9.85 9 9.8 8.8	9.95 9.35 7.8		V
$V_{OL}$	Low level output voltage ( $V_{id} = -1V$ ) $R_L = 100k\Omega$ $R_L = 10k\Omega$ $R_L = 600\Omega$ $R_L = 100\Omega$ $T_{min} \leq T_{amb} \leq T_{max}$ $R_L = 10k\Omega$ $R_L = 600\Omega$		50 650 2300	50 150 800 150 900	mV
$I_o$	Output short circuit current ( $V_{id} = \pm 1V$ ) Source ( $V_o = V_{CC^-}$ ) Sink ( $V_o = V_{CC^+}$ )	45 50	65 75		mA
GBP	Gain bandwidth product ( $A_{VCL} = 100$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $f = 100kHz$ )		1.4		MHz

**Table 5.**  $V_{CC}^+ = 10V$ ,  $V_{CC}^- = 0V$ ,  $R_L$ ,  $C_L$  connected to  $V_{CC}/2$ ,  $T_{amb} = 25^\circ C$  (unless otherwise specified) (continued)

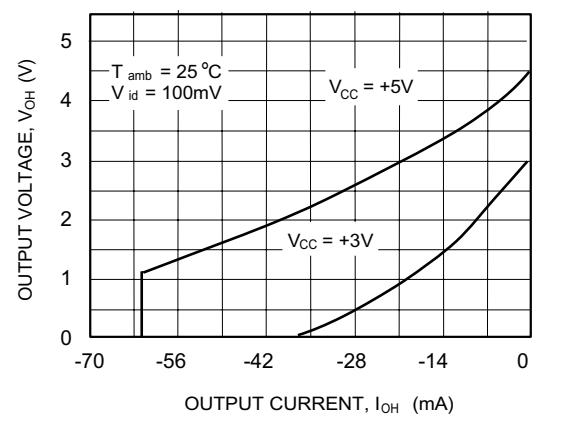
Symbol	Parameter	Min.	Typ.	Max.	Unit
SR <sup>+</sup>	Slew rate ( $A_{VCL} = 1$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $V_i = 2.5V$ to $7.5V$ )		1.3		V/ $\mu$ s
SR <sup>-</sup>	Slew rate ( $A_{VCL} = 1$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $V_i = 2.5V$ to $7.5V$ )		0.8		V/ $\mu$ s
$\phi_m$	Phase margin		40		Degrees
en	Equivalent input noise voltage ( $R_s = 100\Omega$ , $f = 1kHz$ )		30		nV/ $\sqrt{Hz}$
THD	Total harmonic distortion ( $A_{VCL} = 1$ , $R_L = 10k\Omega$ , $C_L = 100pF$ , $V_o = 4.75V$ to $5.25V$ , $f = 1kHz$ )		0.02		%
$C_{in}$	Input capacitance		1.5		pF

1. Maximum values include unavoidable inaccuracies of the industrial tests.

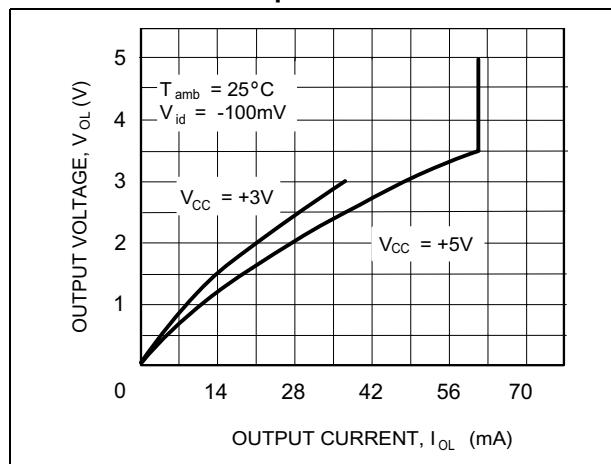
**Figure 2. Supply current (each amplifier) vs. supply voltage**



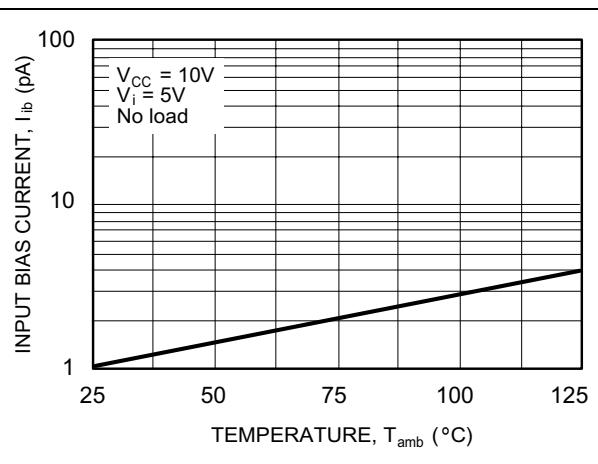
**Figure 3. High level output voltage vs. high level output current**



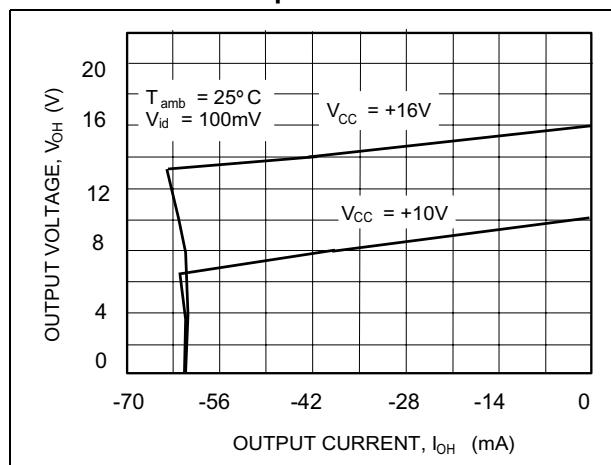
**Figure 4. Low level output voltage vs. low level output current**



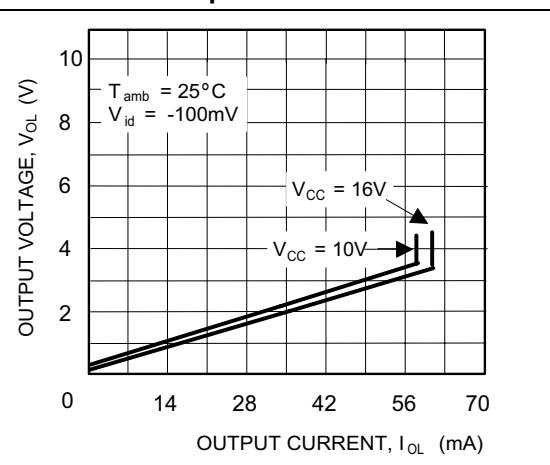
**Figure 5. Input bias current vs. temperature**

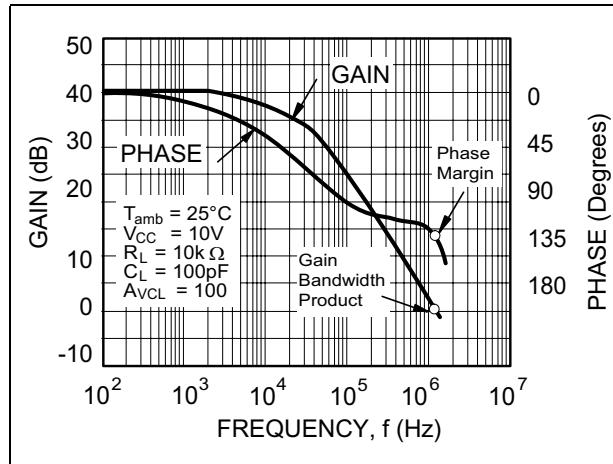
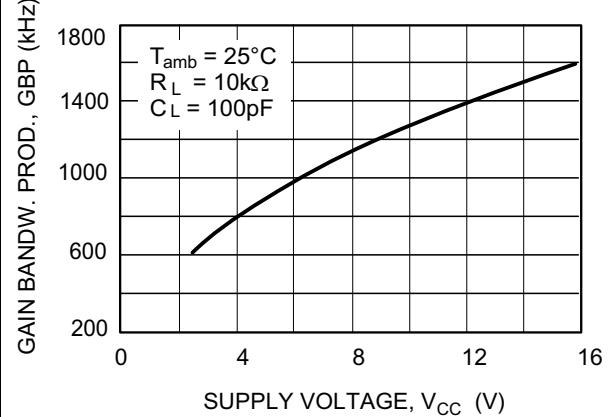
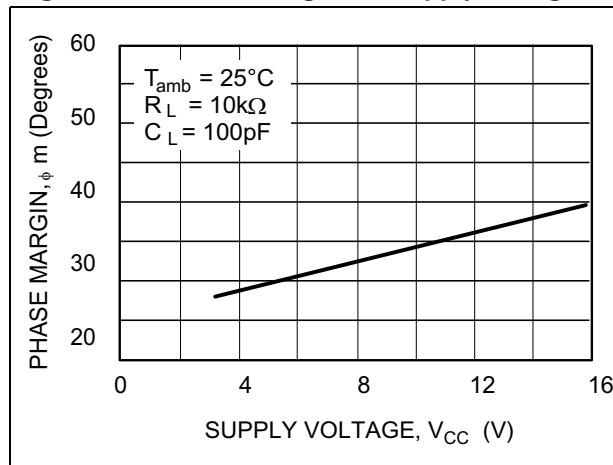
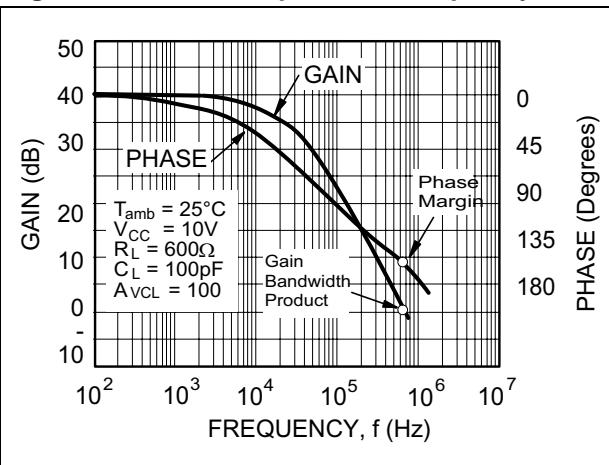
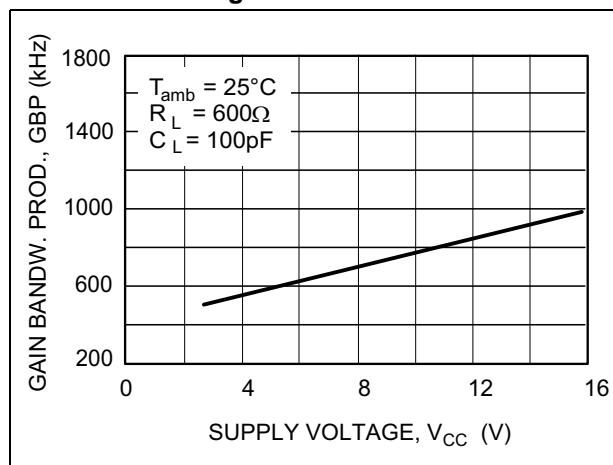
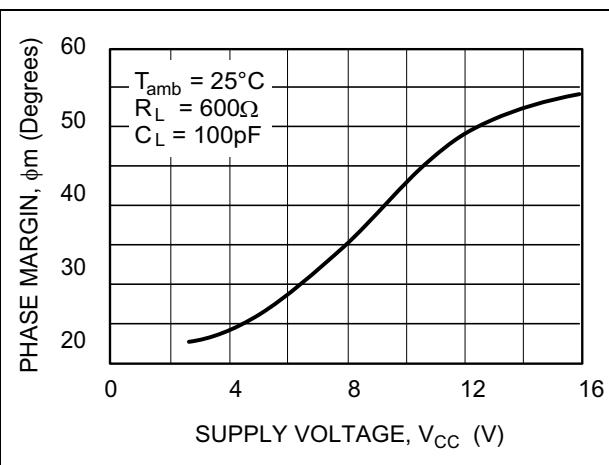


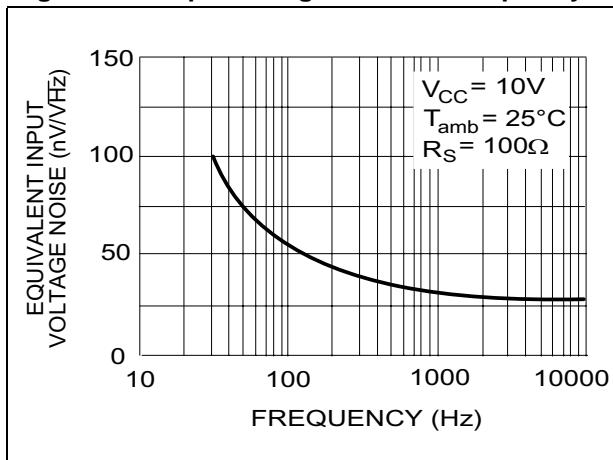
**Figure 6. High level output voltage vs. high level output current**



**Figure 7. Low level output voltage vs. low level output current**



**Figure 8. Gain and phase vs. frequency****Figure 9. Gain bandwidth product vs. supply voltage****Figure 10. Phase margin vs. supply voltage****Figure 11. Gain and phase vs. frequency****Figure 12. Gain bandwidth product vs. supply voltage****Figure 13. Phase margin vs. supply voltage**

**Figure 14. Input voltage noise vs. frequency**

## 4 Macromodel

### 4.1 Important note concerning this macromodel

Please consider the following remarks before using this macromodel.

- All models are a trade-off between accuracy and complexity (i.e. simulation time).
- Macromodels are not a substitute to breadboarding; rather, they confirm the validity of a design approach and help to select surrounding component values.
- A macromodel emulates the **nominal** performance of a **typical** device within **specified operating conditions** (temperature, supply voltage, for example). Thus the macromodel is often not as exhaustive as the datasheet, its purpose is to illustrate the main parameters of the product.

Data derived from macromodels used outside of the specified conditions ( $V_{CC}$ , temperature, for example) or even worse, outside of the device operating conditions ( $V_{CC}$ ,  $V_{icm}$ , for example), is not reliable in any way.

## 4.2 Macromodel code

```
** Standard Linear Ics Macromodels, 1993.  
** CONNECTIONS :  
* 1 INVERTING INPUT  
* 2 NON-INVERTING INPUT  
* 3 OUTPUT  
* 4 POSITIVE POWER SUPPLY  
* 5 NEGATIVE POWER SUPPLY  
.SUBCKT TS912 1 2 3 4 5  
*****  
.MODEL MDTH D IS=1E-8 KF=6.563355E-14 CJO=10F  
* INPUT STAGE  
CIP 2 5 1.500000E-12  
CIN 1 5 1.500000E-12  
EIP 10 5 2 5 1  
EIN 16 5 1 5 1  
RIP 10 11 6.500000E+00  
RIN 15 16 6.500000E+00  
RIS 11 15 7.655100E+00  
DIP 11 12 MDTH 400E-12  
DIN 15 14 MDTH 400E-12  
VOFP 12 13 DC 0.000000E+00  
VOFN 13 14 DC 0  
IPOL 13 5 4.000000E-05  
CPS 11 15 3.82E-08  
DINN 17 13 MDTH 400E-12  
VIN 17 5 -0.5000000e+00  
DINR 15 18 MDTH 400E-12  
VIP 4 18 -0.5000000E+00  
FCP 4 5 VOFP 7.750000E+00  
FCN 5 4 VOFN 7.750000E+00  
* AMPLIFYING STAGE  
FIP 5 19 VOFP 5.500000E+02  
FIN 5 19 VOFN 5.500000E+02  
RG1 19 5 5.087344E+05  
RG2 19 4 5.087344E+05  
CC 19 29 2.200000E-08  
HZTP 30 29 VOFP 12.33E+02  
HZTN 5 30 VOFN 12.33E+02  
DOPM 19 22 MDTH 400E-12  
DONM 21 19 MDTH 400E-12  
HOPM 22 28 VOUT 3135  
VIPM 28 4 150  
HONM 21 27 VOUT 3135  
VINM 5 27 150  
EOUT 26 23 19 5 1  
VOUT 23 5 0  
ROUT 26 3 65  
COUT 3 5 1.000000E-12  
DOP 19 68 MDTH 400E-12  
VOP 4 25 1.924
```

```
HSCP 68 25 VSCP1 1E8
DON 69 19 MDTH 400E-12
VON 24 5 2.4419107
HSCN 24 69 VSCN1 1.5E8
VSCTHP 60 61 0.1375
DSCP1 61 63 MDTH 400E-12
VSCP1 63 64 0
ISCP 64 0 1.000000E-8
DSCP2 0 64 MDTH 400E-12
DSCN2 0 74 MDTH 400E-12
ISCN 74 0 1.000000E-8
VSCN1 73 74 0
DSCN1 71 73 MDTH 400E-12
VSCTHN 71 70 -0.75
ESCP 60 0 2 1 500
ESCN 70 0 2 1 -2000
.ENDS
```

## 5 Package information

In order to meet environmental requirements, ST offers these devices in ECOPACK® packages. These packages have a lead-free second level interconnect. The category of second level interconnect is marked on the package and on the inner box label, in compliance with JEDEC Standard JESD97. The maximum ratings related to soldering conditions are also marked on the inner box label. ECOPACK is an ST trademark. ECOPACK specifications are available at: [www.st.com](http://www.st.com).

## 5.1 DIP-8 package mechanical data

Figure 15. DIP8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			5.33			0.210
A1	0.38			0.015		
A2	2.92	3.30	4.95	0.115	0.130	0.195
b	0.36	0.46	0.56	0.014	0.018	0.022
b2	1.14	1.52	1.78	0.045	0.060	0.070
c	0.20	0.25	0.36	0.008	0.010	0.014
D	9.02	9.27	10.16	0.355	0.365	0.400
E	7.62	7.87	8.26	0.300	0.310	0.325
E1	6.10	6.35	7.11	0.240	0.250	0.280
e		2.54			0.100	
eA		7.62			0.300	
eB			10.92			0.430
L	2.92	3.30	3.81	0.115	0.130	0.150

The figure contains four technical drawings of the DIP-8 package:

- Top View:** Shows the package in a rectangular outline with pins numbered 1 through 8. Dimensions include D (width) and E1 (height).
- Side View:** Shows the package in perspective with dimensions A, A1, A2, b, b2, c, D, E, eA, eB, and E1 labeled.
- Cross-Sectional View:** Shows a vertical cut through the package. It includes a callout 'H' pointing to a horizontal dimension 'E'. A curved arrow points to a 'GAUGE PLANE 0.38' dimension, indicating a measurement point 0.38 units from the bottom edge.
- Front View:** Shows the package in perspective with dimensions A, A1, A2, b, b2, c, D, E, eA, eB, and E1 labeled.

## 5.2 SO-8 package mechanical data

Figure 16. SO-8 package mechanical data

Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
A1	0.10		0.25	0.004		0.010
A2	1.25			0.049		
b	0.28		0.48	0.011		0.019
c	0.17		0.23	0.007		0.010
D	4.80	4.90	5.00	0.189	0.193	0.197
H	5.80	6.00	6.20	0.228	0.236	0.244
E1	3.80	3.90	4.00	0.150	0.154	0.157
e		1.27			0.050	
h	0.25		0.50	0.010		0.020
L	0.40		1.27	0.016		0.050
k	1°		8°	1°		8°
ccc			0.10			0.004

The figure contains three technical drawings of the SO-8 package:

- Top View:** Shows the package from above with pins numbered 1 through 8. Dimensions include height (E1), width (D), lead spacing (b), lead thickness (c), and lead height (h).
- Side View:** Shows the package in cross-section. Dimensions include lead thickness (A), lead height (A1), lead width (A2), lead angle (k), lead height at 45° (h x 45°), lead length (L), and lead gap (ccc).
- Cross-Section:** Shows the package seated on a seating plane (C). Dimensions include lead thickness (A), lead height (A1), lead width (A2), lead angle (k), lead height at 45° (h x 45°), lead length (L), lead gap (ccc), and a gage plane offset of 0.25 mm from the seating plane (GAGE PLANE).

## 6 Ordering information

**Table 6. Order codes**

Part number	Temperature range	Package	Packing	Marking
TS912IN	-40°C, +125°C	DIP8	Tube	TS912IN
TS912AIN				TS912AIN
TS912ID		SO-8	Tube or Tape & reel	912I
TS912IDT				912AI
TS912AID				912BI
TS912AIDT				912IY
TS912BID		SO-8 (Automotive grade level)		912AIY
TS912BIDT				912BY
TS912IYD				
TS912IYDT <sup>(1)</sup>				
TS912AIYD				
TS912AIYDT <sup>(1)</sup>				
TS912BIYD				
TS912BIYDT <sup>(1)</sup>				

1. Qualified and characterized according to AEC Q100 and Q003 or equivalent, advanced screening according to AEC Q001 & Q 002 or equivalent.

## 7 Revision history

**Table 7. Document revision history**

Date	Revision	Changes
4-Dec.-2001	1	First release.
31-Jul-2005	2	PPAP references inserted in the datasheet, see order codes table. ESD protection inserted in AMR table.
3-Oct-2005	3	Some errors in the Order Codes table were corrected. Reorganization of <a href="#">Section 4: Macromodel</a> .
13-Feb- 2006	4	Parameters added in AMR table ( $T_j$ , ESD, $R_{thja}$ , $R_{thjc}$ ).
16-Oct-2007	5	Corrected units and ESD footnotes in <a href="#">Table 1: Absolute maximum ratings</a> . Corrected misalignments in electrical characteristics table. Updated <a href="#">Section 4: Macromodel</a> . Added missing automotive grade order codes and footnote in <a href="#">Table 6: Order codes</a> . Format update.

**Please Read Carefully:**

Information in this document is provided solely in connection with ST products. STMicroelectronics NV and its subsidiaries ("ST") reserve the right to make changes, corrections, modifications or improvements, to this document, and the products and services described herein at any time, without notice.

All ST products are sold pursuant to ST's terms and conditions of sale.

Purchasers are solely responsible for the choice, selection and use of the ST products and services described herein, and ST assumes no liability whatsoever relating to the choice, selection or use of the ST products and services described herein.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted under this document. If any part of this document refers to any third party products or services it shall not be deemed a license grant by ST for the use of such third party products or services, or any intellectual property contained therein or considered as a warranty covering the use in any manner whatsoever of such third party products or services or any intellectual property contained therein.

**UNLESS OTHERWISE SET FORTH IN ST'S TERMS AND CONDITIONS OF SALE ST DISCLAIMS ANY EXPRESS OR IMPLIED WARRANTY WITH RESPECT TO THE USE AND/OR SALE OF ST PRODUCTS INCLUDING WITHOUT LIMITATION IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION), OR INFRINGEMENT OF ANY PATENT, COPYRIGHT OR OTHER INTELLECTUAL PROPERTY RIGHT.**

**UNLESS EXPRESSLY APPROVED IN WRITING BY AN AUTHORIZED ST REPRESENTATIVE, ST PRODUCTS ARE NOT RECOMMENDED, AUTHORIZED OR WARRANTED FOR USE IN MILITARY, AIR CRAFT, SPACE, LIFE SAVING, OR LIFE SUSTAINING APPLICATIONS, NOR IN PRODUCTS OR SYSTEMS WHERE FAILURE OR MALFUNCTION MAY RESULT IN PERSONAL INJURY, DEATH, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE. ST PRODUCTS WHICH ARE NOT SPECIFIED AS "AUTOMOTIVE GRADE" MAY ONLY BE USED IN AUTOMOTIVE APPLICATIONS AT USER'S OWN RISK.**

Resale of ST products with provisions different from the statements and/or technical features set forth in this document shall immediately void any warranty granted by ST for the ST product or service described herein and shall not create or extend in any manner whatsoever, any liability of ST.

ST and the ST logo are trademarks or registered trademarks of ST in various countries.

Information in this document supersedes and replaces all information previously supplied.

The ST logo is a registered trademark of STMicroelectronics. All other names are the property of their respective owners.

© 2007 STMicroelectronics - All rights reserved

STMicroelectronics group of companies

Australia - Belgium - Brazil - Canada - China - Czech Republic - Finland - France - Germany - Hong Kong - India - Israel - Italy - Japan -  
Malaysia - Malta - Morocco - Singapore - Spain - Sweden - Switzerland - United Kingdom - United States of America

[www.st.com](http://www.st.com)